

SPECIFICATION FOR SMT HCMOS OSCILLATOR MtronPTI P/N M2010S186

Electrical Specifications:

Parameter	Symbol	Min.	Typ.	Max.	Units	Conditions
Frequency of Operation	F _O		10.000000		MHz	
Frequency Stability						
Frequency Stability	$\Delta F/F$	-100		+100	ppm	Includes initial tolerance, deviation over temperature, voltage, load, shock, vibration, and aging.
Aging		-10		+10	ppm	Per year.
RF Output						
Output Type		HCMOS Compatible				
Output Load				15	pF	
Symmetry (duty cycle)	T _{DC}	40	50	60	%	Ref to ½ V _{DD}
Logic "1" Level	V _{OH}	4.0			V	HCMOS load
Logic "0" Level	V _{OL}			0.4	V	HCMOS load
Rise/Fall Time	T _R /T _F			10	nS	From 20% to 80% V _{DD}
Start-Up Time				10	mS	
Tri-State Function		70% V _{DD} or N/C			V	Pad 1: Output Enabled
				30% V _{DD}	V	Pad 1: Output Disabled to high-Z
Supply Voltage & Power Consumption						
Operating Voltage	V _{DD}	4.75	5.0	5.25	V	
Operating Current	I _{DD}			20	mA	

Environmental & Mechanical Requirements:

Operating Temperature	T _A	-40		+85	°C	
Storage Temperature	T _S	-55		+125	°C	
Mechanical Shock	Per MIL-STD-202, Method 213, Condition I					
Vibration	Per MIL-STD-202, Method 202 & 204 Condition C					
Thermal Shock	Per MIL-STD-202, Method 207, Condition B					
Seal	Per MIL-STD-202, Method 112, Condition C.					
Max. Soldering Conditions	See solder profile, Figure 1					
Solderability	Per EIAJ-STD-002					
Package Type	4-pad 5 X 7 X 1.9 mm leadless ceramic.					

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Dimensions, Marking, and Pin Out Information:

Pad	Function
1	Tristate
2	Ground
3	Output
4	+V _{DD}

Part Marking	
Line 1	M2010S186
Line 2	10M0000
Line 3	M yy ww vv

Legend	
yy	Year
ww	Work week
vv	Factory code

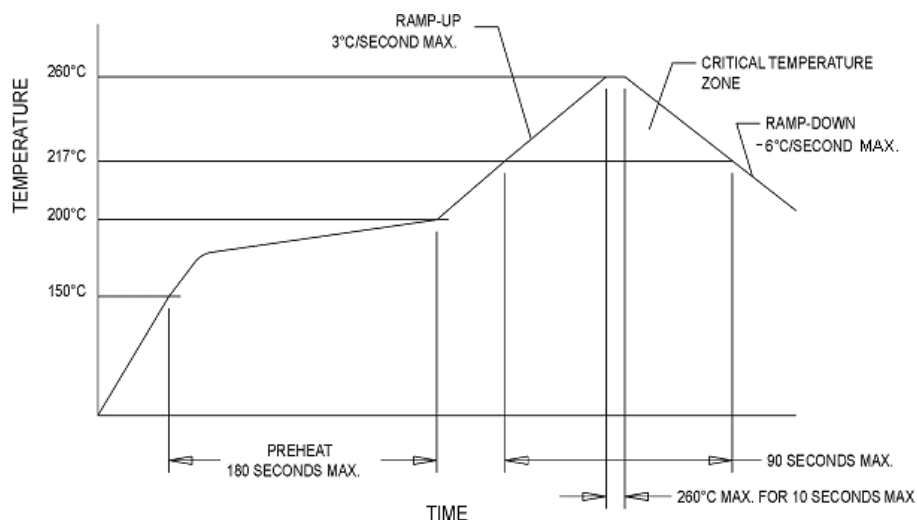
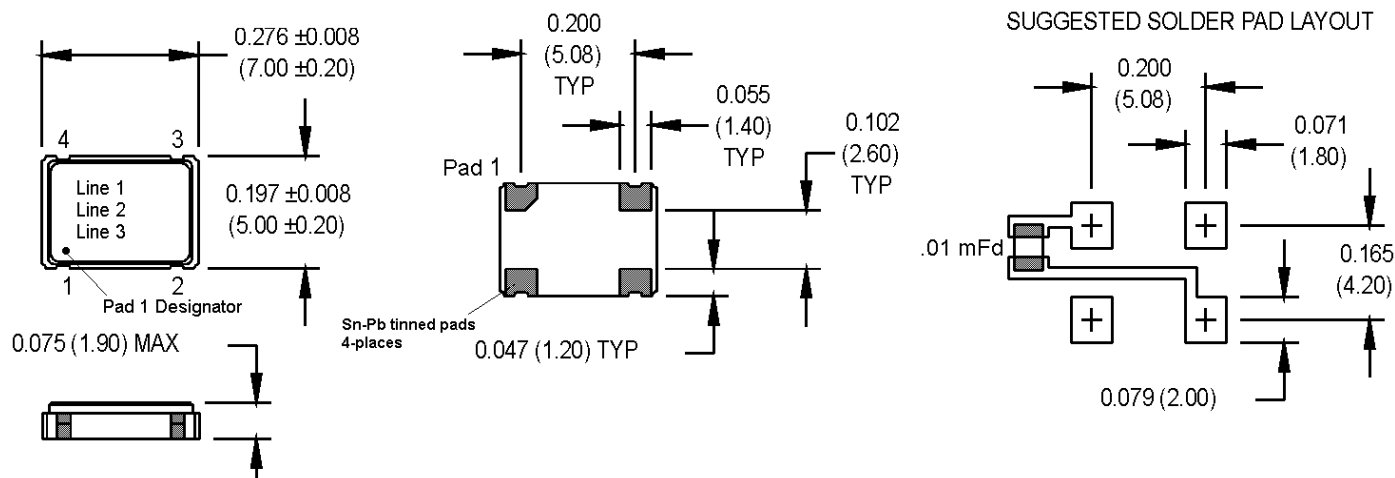


Figure 1

Datasheet Revision Table:

Date	Rev.	Author	Details of Revision
06/02/14	0	MM	Original release.